

December 2013 Rev. 1.0.1

### **GENERAL DESCRIPTION**

The XRP6141 is a synchronous step-down controller for point-of load supplies up to 35A. A wide 4.5V to 22V input voltage range allows for single supply operation from industry standard 5V, 12V and 19.6V rails.

With a proprietary emulated current mode Constant On-Time (COT) control scheme, the XRP6141 provides extremely fast line and load transient response using ceramic output capacitors. It requires no loop compensation hence simplifying circuit implementation and reducing overall component count. control loop also provides exceptional line regulation and maintains constant operating frequency. A selectable power saving mode, allows the user to operate in discontinuous mode (DCM) at light current loads thereby significantly increasing the converter efficiency.

A host of protection features, including overcurrent, over-temperature, short-circuit and UVLO, help achieve safe operation under abnormal operating conditions.

The XRP6141 is available in RoHS compliant, green/halogen free space-saving 16-pin 3x3 QFN package.

#### APPLICATIONS

- Networking and Communications
- Fast Transient Point-of-Loads
- Industrial and Medical Equipment
- Embedded High Power FPGA

### **FEATURES**

- 35A Capable Step Down Controller
  - Wide Input Voltage Range
    - 5V to 22V Single Supply
    - 4.5V to 5.5V Low Vin
  - Integrated high Current 2A/3A Drivers
  - 0.6V to 18V Adjustable Output Voltage
- Proprietary Constant On-Time Control
  - No Loop Compensation Required
  - Ceramic Output Cap. Stable operation
  - Programmable 200ns-2µs
  - Constant 200kHz-800kHz Frequency
  - Selectable CCM or CCM/DCM Operation
- Programmable hiccup current limit with thermal compensation
- Precision Enable and Power-Good Flag
- Programmable Soft-start
- Integrated Bootstrap diode
- 16-pin QFN Package

### TYPICAL APPLICATION DIAGRAM

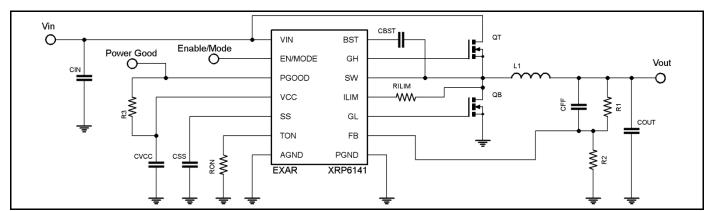


Fig. 1: XRP6141 Application Diagram



#### ABSOLUTE MAXIMUM RATINGS

These are stress ratings only and functional operation of the device at these ratings or any other above those indicated in the operation sections of the specifications below is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

V <sub>IN</sub>	0.3V to 28V
V <sub>CC</sub>	0.3V to 6.0V
BST	0.3V to 34V <sup>2</sup>
BST-SW	0.3V to 6V
SW, ILIM	5V to 28V <sup>1,2</sup>
GH	0.3V to BST+0.3V
GH-SW	0.3V to 6V
ALL other pins	0.3V to VCC+0.3V
Storage Temperature	65°C to 150°C
Junction Temperature	150°C
Power Dissipation	Internally Limited
Lead Temperature (Soldering, 10 sec)	300°C
ESD Rating (HBM - Human Body Model	)2kV

### **OPERATING RATINGS**

V <sub>IN</sub>	0.3V to 22V
V <sub>CC</sub>	0.3V to 5.5V
SW, ILIM	1V to 26V <sup>1</sup>
PGOOD, VCC, TON, SS, EN, GL, FB	0.3V to 5.5V
Switching Frequency	200kHz-800kHz <sup>3</sup>
Junction Temperature Range	40°C to 125°C

Note 1: SW pin's minimum DC range is -1V, transient is

-5V for less than 50ns

Note 2: No external voltage applied

Note 3: Recommended

### **ELECTRICAL SPECIFICATIONS**

Specifications are for Operating Junction Temperature of  $T_J = 25^{\circ}\text{C}$  only; limits applying over the full Operating Junction Temperature range are denoted by a "•". Minimum and Maximum limits are guaranteed through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^{\circ}\text{C}$ , and are provided for reference purposes only. Unless otherwise indicated,  $V_{IN} = 12V$ , BST=VCC, SW=GND=PGND=0V, CGH=CGL=3.3nF.

Parameter	Min.	Тур.	Max.	Units		Conditions
Power Supply Characteristics						
V Input Voltage Dange	5	12	22	V	•	VCC regulating
V <sub>IN</sub> , Input Voltage Range	4.5	5.0	5.5			VCC tied to VIN
$I_{VIN}$ , VIN supply current		0.7	2	mA	•	Not switching, V <sub>IN</sub> =12V, VFB=0.7V
I <sub>VCC</sub> , VCC Quiescent current		0.7	2	mA	•	Not switching, $V_{CC}=V_{IN}=5V$ , VFB=0.7V
$I_{VIN}$ , VIN supply current		11		mA		f=300kHz, RON=108.8k, VFB=0.58V
I <sub>OFF</sub> , Shutdown current		0.1		μΑ		Enable=0V, V <sub>IN</sub> =12V
Enable and Under-Voltage Lock-O	ut UVLO					
V <sub>IH_EN</sub> , EN Pin Rising Threshold	1.8	1.9	2.0	V	•	
V <sub>EN_HYS</sub> , EN Pin Hysteresis		50		mV		
V <sub>IH_EN</sub> , EN Pin Rising Threshold for DCM/CCM operation	2.9	3.0	3.1	٧	•	
V <sub>EN_HYS</sub> , EN Pin Hysteresis		100		mV		
VCC UVLO start threshold, rising edge	4.00	4.25	4.50	٧	•	
VCC UVLO Hysteresis		200		mV		
Reference voltage						
	0.597	0.600	0.603	٧		$V_{IN}$ =5V-22V $\rightarrow$ VCC regulating
V <sub>REF</sub> , Reference voltage	0.596		0.604	٧		$V_{IN}$ =4.5V-5.5V $\rightarrow$ tie VCC to VIN
	0.594	0.600	0.606	V	•	$V_{IN} = 5V-22V \rightarrow VCC \text{ regulating},$ $V_{IN} = 4.5V-5.5V \rightarrow \text{ tie VCC to VIN}$
DC Line regulation		±0.1		%		CCM operation, closed loop, applies to any COUT
DC Load regulation		±0.25		%		CCM operation, closed loop, applies to any



Parameter	Min.	Тур.	Max.	Units		Conditions
						COUT
		l		l		
<b>Programmable Constant On-Time</b>						<del>,</del>
On-Time 1	1855	2182	2509	ns	•	$RON = 141.2k\Omega, V_{IN}=22V$
f corresponding to On-Time 1	217	250	294	kHz		V <sub>IN</sub> =22V, V <sub>OUT</sub> =12V
Minimum Programmable On-Time		109		ns		$RON = 7.059k\Omega, V_{IN}=22V$
On-Time 2	170	200	230	ns	•	$RON = 7.059k\Omega, V_{IN}=12V$
f corresponding to On-Time 2	1618	1375	1196	kHz		$V_{OUT}=3.3V$
f corresponding to On-Time 2	490	417	362	kHz		V <sub>OUT</sub> =1.0V
On-Time 3	391	460	529	ns	•	$RON = 16.235k\Omega, V_{IN}=12V$
Minimum Off-Time		250	350	ns	•	
Diode Emulation Mode		•		•		
Zero crossing threshold	-4	-1		mV		DC value measured during test
SoftStart	•	•		•		-
SS Charge current	-14	-10	-6	μΑ	•	
SS Discharge current	1			mA	•	Fault present
VCC Linear Regulator (VCC should	be tied to	VIN, for	4.5V ≤	V <sub>IN</sub> ≤5.5V	<u>')</u>	
,	4.8	5.0	5.2		<del>-</del>	V <sub>IN</sub> =6V to 22V, Iload=0 to 30mA
VCC Output Voltage	4.51	4.7		V	•	V <sub>IN</sub> =5V, Iload=0 to 20mA
Dropout Voltage	200	300	490	mV	•	I <sub>VCC</sub> =30mA
Power Good Output		I	1	I	<u> </u>	1 155
Power Good Threshold	-10	-7.5	-5	%		
Power Good Hysteresis		2	4	%		
Power Good Sink Current	1			mA		
Protection: OCP, OTP, Short-circu	it	I	1	I		
Hiccup timeout		110		ms		
ILIM pin source current	45	50	55	μA		
ILIM current temperature coeff.		0.4		%/°C		
OCP comparator offset	-8	0	+8	mV	•	
Current limit blanking		100		ns		GL rising>1V
Thermal shutdown threshold <sup>1</sup>		150		°C		Rising temperature
Thermal Hysteresis <sup>1</sup>		15		°C		
VSCTH Feedback pin short-circuit threshold	50	60	70	%	•	Percent of VREF, short circuit is active After PGOOD is up
Output Gate drivers						
GH Pull-Down Resistance		1.35	2.0	Ω		IGH=200mA
			2.0	Ω		
GH Pull-up Resistance		1.8			<b>_</b>	IGH=200mA
GL Pull-Down Resistance GL Pull-up Resistance		1.35 1.7	1.9 2.7	Ω	<b>_</b>	IGL=200mA IGL=200mA
					<b>_</b>	IGL-200IIIA
GH and GL rice time		50		kΩ	<b>_</b>	100/2 to 000/2
GH and GL fall time		35	50	ns		10% to 90%
GH and GL fall time		30	40	ns	<u> </u>	90% to 10%
GL to GH non-overlap time	20	30	60	ns		Measured GL falling edge =1V to GH rising edge =1V, BST=VCC, SW=0V
GH to GL non-overlap time	15	20	40	ns		Measured GH falling edge =1V to GL rising edge =1V

Note 1: Guaranteed by design

#### **BLOCK DIAGRAM**

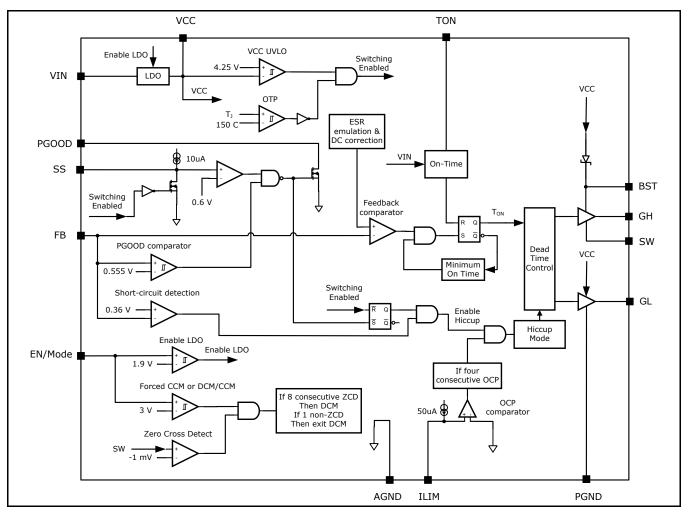


Fig. 2: XRP6141 Block Diagram

### **PIN ASSIGNMENT**

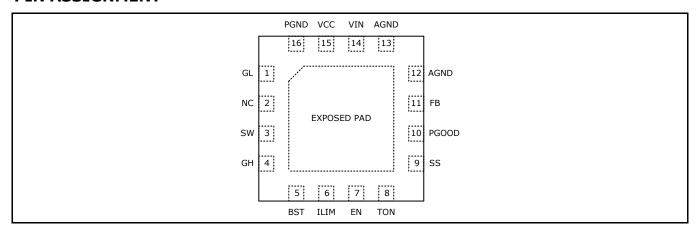


Fig. 3: XRP6141 Pin Assignment



### **PIN DESCRIPTION**

Name	Pin Number	Description				
GL	1	Driver output for Low-side N-channel synchronous MOSFET.				
NC	2	Internally not connected. Leave this pin floating.				
SW	3	Lower supply rail for high-side gate driver GH. Connect this pin to the junction between the two external N-channel MOSFETs.				
GH	4	Driver output for high-side N-channel switching MOSFET.				
BST	5	High-side driver supply pin. Connect a 0.1uF bootstrap capacitor between BST and SW.				
ILIM	6	Over-current protection programming. Connect with a resistor to the Drain of the low-side MOSFET.				
EN/MODE	7	Precision enable pin. Pulling this pin above 1.9V will turn the IC on and it will operate in Forced CCM. If the voltage is raised above 3.0V then the IC will operate in DCM or CCM depending on load.				
TON	8	Constant on-time programming pin. Connect with a resistor to AGND.				
SS	9	Soft-Start pin. Connect an external capacitor between SS and AGND to program the soft-start rate based on the 10uA internal source current.				
PGOOD	10	Power-good output. This open-drain output is pulled low when $V_{\text{OUT}}$ is outside the regulation.				
FB	11	Feedback input to feedback comparator. Connect with a set of resistors to VOUT and GND in order to program $V_{\text{OUT}}$ .				
AGND	12, 13	Analog ground. Control circuitry of the IC is referenced to this pin.				
VIN	14	IC supply input. Provides power to internal LDO.				
VCC	15	The output of LDO. For operation using a 5V rail, VCC should be shorted to VIN.				
PGND	16	Low side driver ground				
Exposed Pad		Thermal pad for heat dissipation. Connect to AGND with a short trace.				

### **ORDERING INFORMATION**

Part Number	Temperature Range	Marking	Package	Packing Quantity	Note 1
XRP6141EL-F	-40°C≤T <sub>J</sub> ≤+125°C	6141	3x3mm QFN16	Tray	Lead Free and/or Halogen Free
XRP6141ELMTR-F	-40°C≤T <sub>J</sub> ≤+125°C	YWW		I /5II/ I AND XI KDDI	
XRP6141ELTR-F	-40°C≤T <sub>J</sub> ≤+125°C	XXXX		3k/Tape & Reel	
XRP6141EVB	XRP6141 Evaluation Board				

<sup>&</sup>quot;Y" = Year - "WW" = Work Week - "X" = Lot Number; when applicable.

### TYPICAL PERFORMANCE CHARACTERISTICS

All data taken at  $V_{\text{IN}} = 12\text{V}$ ,  $V_{\text{OUT}} = 1.2\text{V}$ , f = 300kHz,  $T_{\text{A}} = 25^{\circ}\text{C}$ , unless otherwise specified - Schematic and BOM from Application Information section of this datasheet.

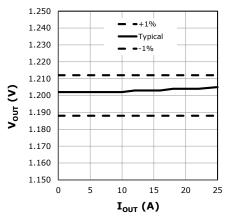


Fig. 4: Load regulation,  $V_{IN}=12V$ 

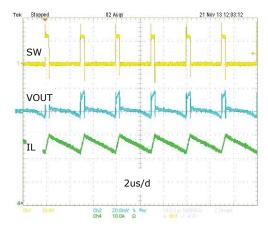


Fig. 6:  $V_{OUT}$  ripple is 22mV at 25A, 12 $V_{IN}$ , 1.2 $V_{OUT}$ 

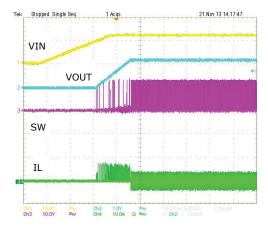


Fig. 8: Powerup, Forced CCM,  $I_{OUT}$ =0A

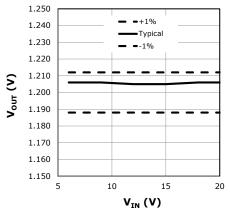


Fig. 5: Line regulation,  $I_{\text{OUT}} = 25 A$ 

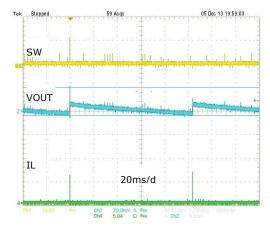


Fig. 7: V<sub>OUT</sub> ripple is 22mV at 0A, DCM, 12V<sub>IN</sub>, 1.2V<sub>OUT</sub>

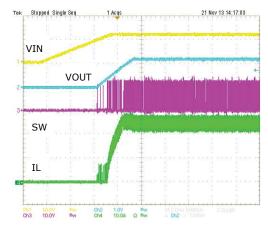


Fig. 9: Powerup, Forced CCM, I<sub>OUT</sub>=25A



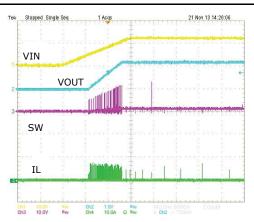


Fig. 10: Powerup, DCM/CCM,  $I_{OUT}$ =0A

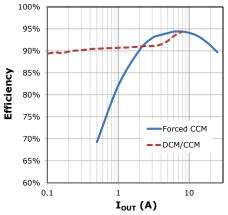


Fig. 12: Efficiency, 5V<sub>IN</sub>, 1.8V<sub>OUT</sub>, 0.47uH, 300kHz

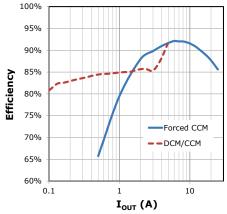


Fig. 14: Efficiency,  $5V_{IN}$ ,  $1.0V_{OUT}$ , 0.47uH, 300kHz

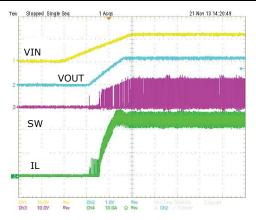


Fig. 11: Powerup, DCM/CCM, I<sub>OUT</sub>=25A

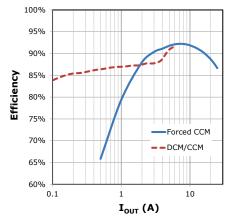


Fig. 13: Efficiency,  $5V_{IN}$ ,  $1.2V_{OUT}$ , 0.47uH, 300kHz

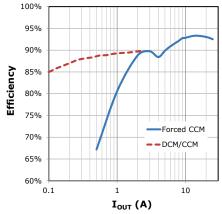


Fig. 15: Efficiency,  $12V_{IN}$ ,  $3.3V_{OUT}$ , 1uH, 300kHz



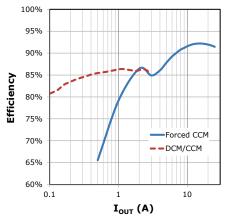


Fig. 16: Efficiency,  $12V_{\text{IN}}$ ,  $2.5V_{\text{OUT}}$ , 1uH, 300kHz

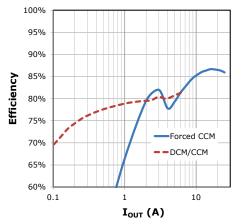


Fig. 18: Efficiency,  $12V_{IN}$ ,  $1.2V_{OUT}$ , 0.47uH, 300kHz

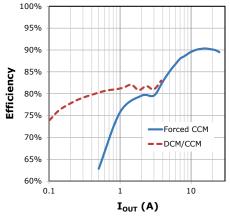


Fig. 17: Efficiency,  $12V_{IN}$ ,  $1.8V_{OUT}$ , 1uH, 300kHz

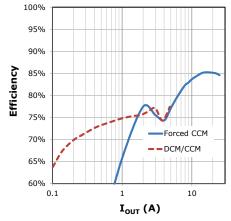


Fig. 19: Efficiency,  $12V_{IN}$ ,  $1.0V_{OUT}$ , 0.47uH, 300kHz

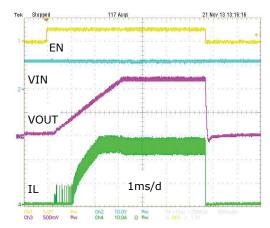


Fig. 20: Enable turn on/turn off,  $12V_{IN}$ ,  $1.2V_{OUT}$ , 25A



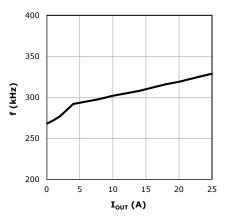


Fig. 22: frequency versu I<sub>OUT</sub>, Forced CCM

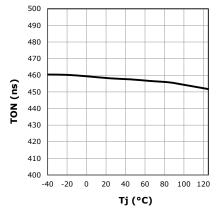


Fig. 24: On-Time versus temperature

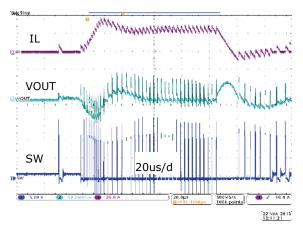


Fig. 26: Load step, DCM/CCM, 0A-25A-0A

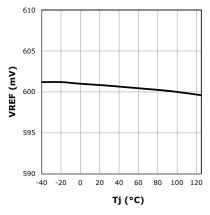


Fig. 23: VREF versus temperature

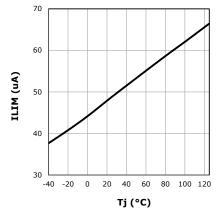


Fig. 25: ILIM versus temperature

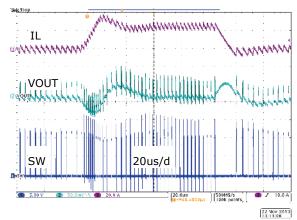


Fig. 27: Load step, Forced CCM, 0A-25A-0A



#### **DETAILED OPERATION**

XRP6141 is a synchronous step-down proprietary emulated current-mode Constant On-Time (COT) controller. The on-time, which is programmed via RON, is inversely proportional to VIN and maintains a nearly constant frequency. The emulated current-mode control allows the use of ceramic output capacitors.

Each switching cycle begins with GH signal turning the high-side (switching) FET for a preprogrammed time. At the end of the on-time the high-side FET is turned off and the low-side (synchronous) FET is turned on for a preset minimum time (250ns nominal). This parameter is termed Minimum Off-Time. After the minimum off-time the voltage at the feedback pin FB is compared to an internal voltage ramp at the feedback comparator. When VFB drops below the ramp voltage, the high-side FET is turned on and the cycle repeats. This voltage ramp constitutes an emulated current ramp and makes possible the use of ceramic capacitors, in addition to other capacitor types, for output filtering.

### **ENABLE/MODE**

EN/MODE pin accepts a tri-level signal that is used to control turn on/off. It also selects between two modes of operation: 'Forced CCM' and 'DCM/CCM'. If EN is pulled below 1.9V the IC shuts down. A voltage between 1.9V and 3V selects the Forced CCM mode, which will run the converter in continuous conduction at all times. A voltage higher than 3V selects the DCM/CCM mode, which will run the converter in discontinuous conduction at light loads. DCM/CCM, which is based on diode emulation, is described below.

### Diode Emulation Mode (DCM/CCM)

Diode Emulation Mode is designed to increase the converter efficiency at light loads. Light-load efficiency is increased by preventing negative inductor current. This is achieved by monitoring the inductor current valley (bottom) via SW and turning off the synchronous FET as inductor current  $I_L$  approaches zero.  $I_L$  is monitored indirectly by monitoring V<sub>SW</sub> during the synchronous FET conduction (i.e.,  $V_{SW}=I_L \times Rds$ ). If  $V_{SW}$  does not drop to -1mV the converter operates in continuous conduction as shown in figure 28. If  $V_{\text{SW}}$  equals -1mV then a zero-crossing is detected (figure 29). Eight consecutive zerocrossings activate the diode emulation mode. Then, on every subsequent switching cycle, GL is turned off when V<sub>SW</sub> reaches -1mV (figure 30). If IOUT decreases further, discontinuous conduction ensues (figure 30). The constant on-time delivers a fixed energy at the start of each switching cycle. The synchronous FET is turned off when  $V_{\text{SW}}$  drops to -1mV. Remaining inductor energy is discharged through the FET's body diode. Now, because IOUT is low, it takes longer for VOUT to drop below regulation and trigger a new switching cycle. Hence switching frequency f decreases. This increase the efficiency at light loads.

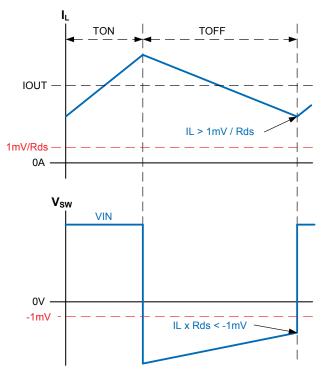


Figure 28. Continuous conduction during diode emulation

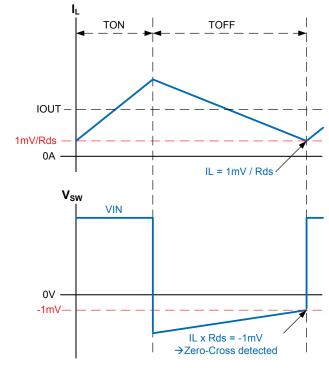


Figure 29. Zero-Crossing detection

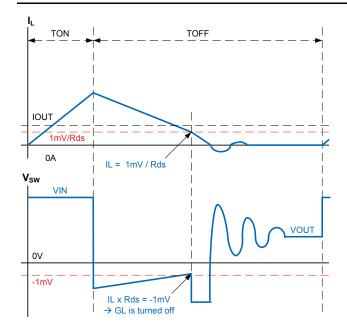


Figure 30. Discontinuous conduction during diode emulation

### **PROGRAMMING THE ON-TIME**

The on-time TON is programmed via resistor RON according to following equation:

$$TON = \frac{(3.4E - 10) \times RON}{VIN}$$

The required TON for a given application is calculated from:

$$TON = \frac{VOUT}{VIN \times f}$$

Note that switching frequency f will increase somewhat, as a function of increasing load current and increasing losses (see figure 22).

### **OVER-CURRENT PROTECTION (OCP)**

If load current exceeds the programmed overcurrent IOCP for four consecutive switching cycles, then IC enters hiccup mode of operation. In hiccup the MOSFET gates are turned off for 110ms (hiccup timeout). Following the hiccup timeout a soft-start is attempted. If OCP persists, hiccup timeout will repeat. The IC will remain in hiccup mode until load current is reduced below the programmed IOCP. In order to program overcurrent protection use the following equation:

$$RLIM = \frac{(IOCP \times RDS) + 8mV}{ILIM}$$

#### Where:

RLIM is resistor value for programming IOCP

IOCP is the overcurrent value to be programmed

RDS is the MOSFET rated on resistance

8mV is the OCP comparator offset

ILIM is the internal current that generates the necessary OCP comparator threshold (use 45uA)

Note that ILIM has a positive temperature coefficient of 0.4%/°C. This is meant to roughly match and compensate for positive temperature coefficient of the synchronous FET. In order for this feature to be effective the temperature rise of the IC should approximately match the temperature rise of the FET.

### SHORT-CIRCUIT PROTECTION (SCP)

If the output voltage drops below 60% of its programmed value, the IC will enter hiccup mode. Hiccup will persist until short-circuit is removed. SCP circuit becomes active after PGOOD asserts high.

### **OVER-TEMPERATURE PROTECTION (OTP)**

OTP triggers at a nominal die temperature of 150°C. The gate of switching FET and synchronous FET are turned off. When die temperature cools down to 135°C, softstart is initiated and operation resumes.

### PROGRAMMING THE OUTPUT VOLTAGE

Use an external voltage divider as shown in figure 1 to program the output voltage VOUT.

$$R1 = R2 \times \left(\frac{VOUT}{0.6} - 1\right)$$

R2 recommended range is  $2k\,\Omega$  to  $10k\Omega.$ 

### **PROGRAMMING THE SOFTSTART**

Place a capacitor CSS between the SS and GND pins to program the softstart. In order to program a softstart time of TSS, calculate the required capacitance CSS from the following equation:

$$CSS = TSS \times \frac{10uA}{0.6V}$$

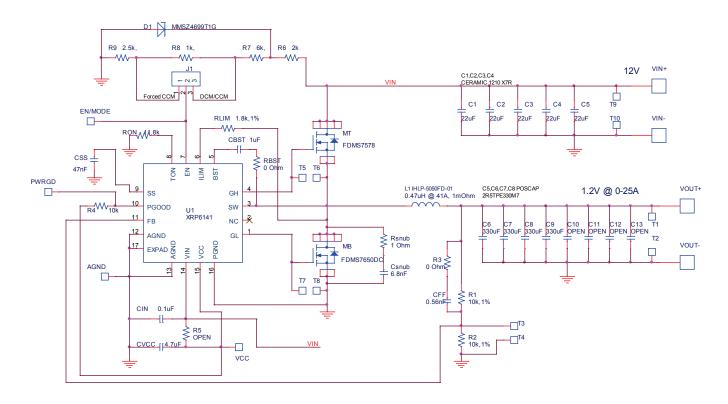
#### FEED-FORWARD CAPACITOR CFF

A feed-forward capacitor CFF is recommended. CFF provides a low-impedance/high-frequency path for the output voltage ripple to be transmitted to FB. It also helps get an optimum load transient response. Calculate CFF from:

$$CFF = \frac{1}{2 \times \pi \times fs \times 0.1 \times R1}$$



### **Applications Circuit**



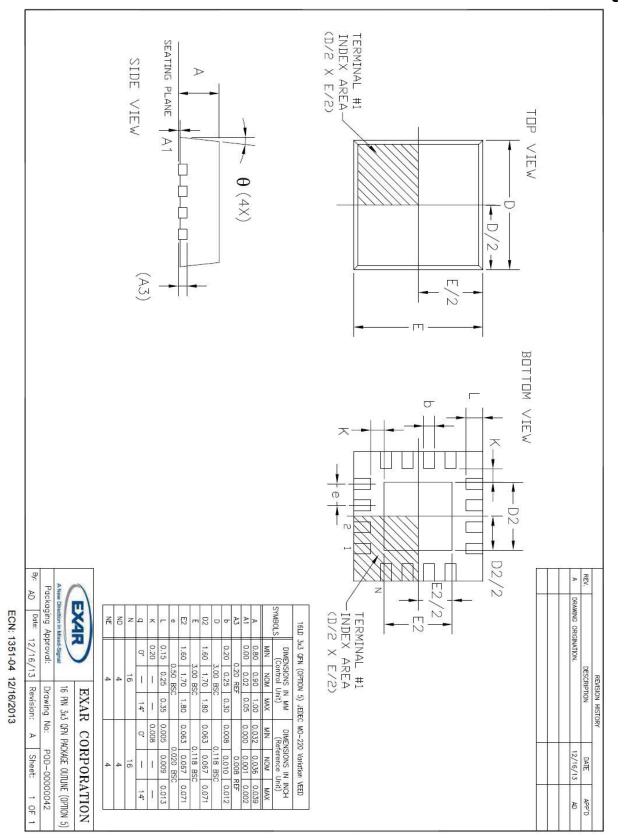
Note: If jumper J1 is set to CCM position, the converter will operate in `Forced CCM' at VIN=12V(+/-10%). In order to operate in Forced CCM over a wider VIN range, remove Jumper and apply an auxiliary voltage in the 1.9V-3V range to the EN/MODE test point.

If jumper J1 is set to DCM/CCM position the converter will operate at DCM or CCM, depending on load, at VIN=12V(+/-10%). In order to operate in DCM/CCM over a wider VIN range, remove Jumper and apply an auxiliary voltage in the 3.1V-5V range to the EN/MODE test point.



### **PACKAGE SPECIFICATION**

# **16 PIN 3X3 QFN**





#### **REVISION HISTORY**

Revision	Date	Description
1.0.0	12/16/2013	Initial release
1.0.1	12/20/2013	Specification improvement

### FOR FURTHER ASSISTANCE

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